Thyristor Semiconductor Device - Page 1 of 1



that reflect specification type data in specification

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Inclosure Material:	
Metal	
Overall Length:	
Between 0.240 inches and 0.	260 inches
Terminal Length:	
Between 1.500 inches and 1.	750 inches
Overall Diameter:	
Between 0.335 inches and 0.	370 inches
Internal Configuration:	
Junction contact	
Electrode Internally-electric	cally Connected To Case:
Anode	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.200 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per	Characteristic:
2.2 forward voltage, peak a	nd 0.9 gate trigger voltage, dc and 100.0 reverse voltage, peak
Current Rating Per Charact	eristic:
75.00 microamperes forward	current, total rms preset and 220.00 milliamperes forward current, total rms megahertz
Maximum Operating Temp	urature Per Measurement Point:
125.0 degrees celsius ambie	nt air
Special Features:	
Junction pattern arrangemen	t: pnpn
Test Data Document:	
81349-mil-s-19500 specificat	ion (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
-	I catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performar	nce requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantit	
3 uninsulated wire lead	·
Specification Data:	
81349-mil-s-19500/276 gove	rnment specification
Shelf Life:	·
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
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